RDE Series (Only for Commercial) Specifications and Test Methods

	No. Item		Specifications						
No.			Temperature Compensating Type	High Dielectric Constant Type	Test Method				
1	Operating Temperature Range		-55 to +125°C	Char. X7R, X7S: -55 to +125°C Char. F: -25 to +85°C Char. Y5V: -30 to +85°C	-				
2	Appearance		No defects or abnormalities		Visual inspection				
3	Dimension an	d Marking	See previous pages		Visual inspection, Vernier Caliper				
4	Dielectric	Between Terminals	No defects or abnormalities		The capacitors should not be damaged whe voltages of Table are applied between the te for 1 to 5 sec. (Charge/Discharge current ≤ Temperature Compensating Type Rated Voltage DC50V, DC100V High Dielectric Constant Type Rated Voltage DC25V, DC50V DC100V, DC50V DC100V, DC250V DC100V, DC250V DC630V Test Voltage DC25V, DC50V DC100V, DC250V DC100V, DC250V DC630V Test Voltage DC25V, DC50V DC100V, DC250V DC100V, DC250V		on the terminals Irrent ≤ 50mA) Voltage rated voltage rated voltage rated voltage rated voltage rated voltage		
4	Strength	Body Insulation	No defects or abnormalities		The capacitor is placed in a container with metal balls of 1mm diameter so that each terminal, short-circuited, is kept approximately 2mm from the balls as shown in the figure, and 250% of the rated voltage (200% of the rated voltage in case of rated voltage: DC100V, DC250V, DC630V) is impressed for 1 to 5 sec. between capacitor terminals and metal balls. (Charge/Discharge current ≤ 50mA)				
5	Insulation Resistance	Between Terminals	Rated Voltage: DC25V, DC50V, DC100V 10,000MΩ min. or 500MΩ • μ F min. whichever is smaller Rated Voltage: DC250V, DC630V 10,000MΩ min. or 100MΩ • μ F min. whichever is smaller		The insulation resistance should be measured with a DC voltage not exceeding the rated voltage (DC500±50V in case of rated vlotage: DC630V) at normal temperature and humidity and within 2 min. of charging. (Charge/Discharge current ≤ 50mA)				
6	Capacitance		Within the specified tolerance		The capacitance, Q/D.F. should be measured at 25°C				
					at the frequency and Temperature Comparitance Item	d voltage shown pensating Type C≦1000pF 1±0.1MHz	C>1000pF		
	Q/Dissipation Factor (D.F.)		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	Char. X7R: 0.025 max.	Voltage	AC0.5 to 5V (r.m.s.)	AC1±0.2V (r.m.s.)		
7			30pF max.: Q≥400+20C C: Nominal capacitance (pF)	Char. F, Y5V: 0.05 max. Char. X7S: 0.125 max.	High Dielectric Constant Type Capacitance		C>10μF		
							Frequency	1±0.1kHz	120±24Hz
					Voltage	AC1±0.2V (r.m.s.)	AC0.5±0.1V (r.m.s.)		

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RDE Series (Only for Commercial) Specifications and Test Methods

 $\begin{tabular}{|c|c|c|c|}\hline \end{tabular}$ Continued from the preceding page.

No.	o. Item		Specifi	cations		Test Method	
			Temperature Compensating Type High Dielectric Constant Type		rest iniethod		
		Capacitance Change	Within the specified tolerance (Table A on last column)	Within the specified tolerance (Table B on last column)	The capacitance change should be measured after 5 min. at each specified temperature stage. (1) Temperature Compensating Type The temperature coefficient is determined using the capacitance measured in step 3 as a reference. Whe cycling the temperature sequentially from step 1 through 5 (-55 to +125 °C) the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as shown in Tab A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in step 1, 3 and 5 by the cap. value step 3. Step Temperature (°C) 1 25±2		
8	Capacitance Temperature	Temperature Coefficient	Within the specified tolerance (Table A on last column)				
	Characteristics				2	-55±3	
					3	25±2	
					5	125±3 25±2	
		Capacitance Drift	Within ±0.2% or ±0.05pF (whichever is larger)		25°C (Char. F: 20°c ranges as shown in specified ranges. • Pretreatment (for Perform a heat treatment)	Constant Type acitance change compared with the C) value over the temperature a Table B should be within the high dielectric constant type) atment at 150+0/-10°C for 1 hr., and temperature for 24±2 hrs.	
9	Terminal Strength	Tensile Strength	Termination not to be broken or loosened		As in the figure, fix the capacitor body, apply the force gradually to each lead in the radial direction of the capacitor until reaching 10N and then keep the force applied for 10±1 sec.		
		Bending Strength	Termination not to be broken or loosened		Each lead wire should be subjected to a force of 2.5N and then bent 90° at the point of egress in one direction. Each wire is then returned to the original position and bent 90° in the opposite direction at the rate of one bend per 2 to 3 sec.		
		Appearance	No defects or abnormalities		The capacitor is soldered securely to a support		
	Vibration Resistance	Capacitance	Within the specified tolerance			o 55Hz vibration of 1.5mm peak-	
10		Q/D.F.	30pF min.: Q≥1,000 30pF max.: Q≥400+20C C: Nominal capacitance (pF)	Char. X7R: 0.025 max. Char. F, Y5V: 0.05 max. Char. X7S: 0.125 max.	peak amplitude is applied for 6 hrs. total, 2 hrs. i mutually perpendicular direction. Allow 1 min. to the frequency from 10Hz to 55Hz and the conve		
11	Solderability of Leads		Lead wire should be soldered with uniform coating on the axial direction over 3/4 of the circumferential direction.		The terminal of a capacitor is dipped into a 25% ethano (JIS-K-8101) solution of rosin (JIS-K-5902) and then into molten solder for 2±0.5 sec. In both cases th depth of dipping is up to about 1.5mm to 2mm from the terminal body. Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Ct 235±5°C H60A or H63A Eutectic Solder		
		Appearance	No defects or abnormalities		The lead wire is im	mersed in the malted solder 1 5mm	
	Resistance to Soldering Heat	Capacitance Change	Within ±2.5% or ±0.25pF (whichever is larger)	Char. X7R, X7S: Within ±10% Char. F, Y5V: Within ±20%	to 2mm from the m sec.	mersed in the melted solder 1.5mm ain body at 350±10°C for 3.5±0.5	
12		Dielectric Strength (Between Terminals)	Pretreatment (for high No defects Perform a heat treatment then let sit at room tem		ms are measured after 24±2 hrs. or high dielectric constant type) reatment at 150+0/-10°C for 1 hr., and on temperature for 24±2 hrs.		

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RDE Series (Only for Commercial) Specifications and Test Methods

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Vo.	Ito	m	Specifi	cations		Test Method		
NO.	o. Item		Temperature Compensating Type	High Dielectric Constant Type	rest Method			
	Appearance		No defects or abnormalities					
13		Capacitance Change	Within ±5% or ±0.5pF (whichever is larger)	Char. X7R, X7S: Within ±12.5% Char. F, Y5V: Within ±30%	The capacitor should be sudjected to 5 temperature cycles.			
		Q/D.F.	30pF min.: Q≧350 10pF to 30pF: Q≧275+5C/2 10pF max.: Q≧200+10C	Char. X7R: 0.05 max. Char. F, Y5V: 0.075 max.	Remove and set for 24±2 hrs. at room temperathen measure.			
	Temperature		C: Nominal capacitance (pF)	Char. X7S: 0.2 max.	Step 1	Temperature (°C) Min. Operating Temp. ±3	Time (min) 30±3	
	Cycle	Insulation Resistance	Rated Voltage: DC25V, DC50V, 1,000MΩ, 50MΩ • μF min. (wh Rated Voltage: DC250V, DC630 1,000MΩ, 10MΩ • μF min. (wh	nichever is smaller) VV	2 3 4	Room Temp. Max. Operating Temp. ±3 Room Temp. ent (for high dielectric constar	3 max. 30±3 3 max.	
		Dielectric Strength (Between Terminals)	No defects or abnormalities		Perform a heat treatment at 150+0/-10°C for 1 hr., a then let sit at room temperature for 24±2 hrs.			
		Appearance	No defects or abnormalities					
14		Capacitance Change	Within ±5% or ±0.5pF (whichever is larger)	Char. X7R, X7S: Within ±15% Char. F, Y5V: Within ±30%	Set the capacitor at 40±2°C and relative humidity of			
	Humidity (Steady State)	Q/D.F.	30pF min.: Q≧350 10pF to 30pF: Q≥275+5C/2 10pF max.: Q≥200+10C C: Nominal capacitance (pF)	Char. X7R: 0.05 max. Char. F, Y5V: 0.075 max. Char. X7S: 0.2 max.	90 to 95% for 500 ^{±2} / ₀ hrs. Remove and set for 24±2 hrs. at room temperatu then measure. • Pretreatment (for high dielectric constant type)			
		Insulation Resistance	Rated Voltage: DC25V, DC50V, 1,000MΩ, 50MΩ • μF min. (wh Rated Voltage: DC250V, DC630 1,000MΩ, 10MΩ • μF min. (wh	nichever is smaller) VV	Perform a heat treatment at 150+0/-10°C for 1 hr., and then let sit at room temperature for 24±2 hrs.			
15	Humidity Load	Appearance	No defects or abnormalities					
		Capacitance Change	Within ±7.5% or ±0.75pF (whichever is larger)	Char. X7R, X7S: Within ±15% Char. F, Y5V: Within ±30%	Apply the rated voltage for 500^{+24}_{-0} hrs. at $40\pm2^{\circ}$ C in 90 to 95% humidity.			
		Q/D.F.	30pF min.: Q≥200 30pF max.: Q≥100+10C/3 C: Nominal capacitance (pF)	Char. X7R: 0.05 max. Char. F, Y5V: 0.075 max. Char. X7S: 0.2 max.	Remove and set for 24±2 hrs. at room ten then measure. (Charge/Discharge current ≤50mA)		•	
		Insulation Resistance	Rated Voltage: DC25V, DC50V, 500MΩ or 25MΩ • μF min. (wh Rated Voltage: DC250V, DC630 1,000MΩ or 10MΩ • μF min. (v	nichever is smaller) V	Pretreatment (for high dielectric constant type) Perform a heat treatment at 150+0/-10°C for 1 hr., ar then let sit at room temperature for 24±2 hrs.			
		Appearance	No defects or abnormalities					
16	High Temperature Load	Capacitance Change	Within ±3% or ±0.3pF (whichever is larger)	Char. X7R, X7S: Within ±15% Char. F, Y5V: Within ±30%	maximum op	e in Table for 1000 ⁺⁴⁸ hrs. perating temperature±3°C.		
		Dept to 30pF: 10pF to 30pF: 10pF max.: Q: C: Nominal ca	30pF min.: Q≥350 10pF to 30pF: Q≥275+5C/2 10pF max.: Q≥200+10C	Char. X7R: 0.05 max. Char. F, Y5V: 0.075 max.	1	d set for 24±2 hrs. at room te re. (Charge/Discharge currer tage Test Voltage	nt ≦50mA)	
			C: Nominal capacitance (pF)	Char X/S: 0.2 may		250V 150% of the rated		
			Rated Voltage: DC25V, DC50V, DC100V		DC630V 120% of the rated voltag		l voltage	
		Insulation Resistance	1,000MΩ, 50MΩ • μF min. (wh Rated Voltage: DC250V, DC630	μF min. (whichever is smaller)		Pretreatment (for high dielectric constant type) Appy test voltage for 1 hr., at test temperature. Remove and see for 24±2 hrs. at room temperature.		
		Appearance	No defects or abnormalities		The capacito	or should be fully immersed,	unagitated, i	
17	Solvent Resistance	Marking	Legible		reagent at 20 to 25°C for 30±5 sec. and then remove gently. Marking on the surface of the capacitor shoul immediately be visually examined. Reagent: Isopropyl alcohol			

Table A

	Nominal Values	Capacitance Change from 25°C (%)					
Char.	(ppm/°C) *1	−55°C		−30°C		-10°C	
	(ppin/ c) i	Max.	Min.	Max.	Min.	Max.	Min.
COG	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11

^{*1:} Nominal values denote the temperature coefficient within a range of 25 to 125°C

Table B

Char.	Temp. Range	Reference Temp.	Cap. Change Rate	
X7R	−55 to +125°C		Within ±15%	
X7S	-33 to +123 C	25°C	Within ±22%	
Y5V	−30 to + 85°C		Within ±62%	
F	−25 to + 85°C	20°C	Within ±38%	

